

RJH1CM7DPQ-E0

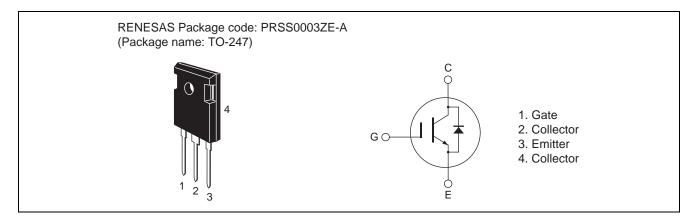
1200V - 25A - IGBT Application: Inverter

R07DS0522EJ0300 Rev.3.00 Jan 19, 2012

Features

- Short circuit withstand time (10 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 2.1 \text{ V typ.}$ (at $I_C = 25 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Built-in fast recovery diode ($t_{rr} = 200 \text{ ns typ.}$) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 100 ns typ. (at V_{CC} = 600 V, V_{GE} = 15 V, I_C = 25 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

| Item | | Symbol | Ratings | Unit |
|--|------------|-----------------------------------|-------------|------|
| Collector to emitter voltage / diode reverse voltage | | V _{CES} / V _R | 1200 | V |
| Gate to emitter voltage | | V_{GES} | ±30 | V |
| Collector current | Tc = 25°C | I _C | 50 | Α |
| | Tc = 100°C | I _C | 25 | Α |
| Collector peak current | | ic(peak) Note1 | 100 | Α |
| Collector to emitter diode forward current | | I _{DF} | 25 | Α |
| Collector to emitter diode forward peak current | | i _{DF} (peak) Note1 | 100 | Α |
| Collector dissipation | | P _C Note2 | 328.9 | W |
| Junction to case thermal resistance (IGBT) | | θj-c Note2 | 0.38 | °C/W |
| Junction temperature | | Tj | 150 | °C |
| Storage temperature | | Tstg | -55 to +150 | °C |

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

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Electrical Characteristics

 $(Ta = 25^{\circ}C)$

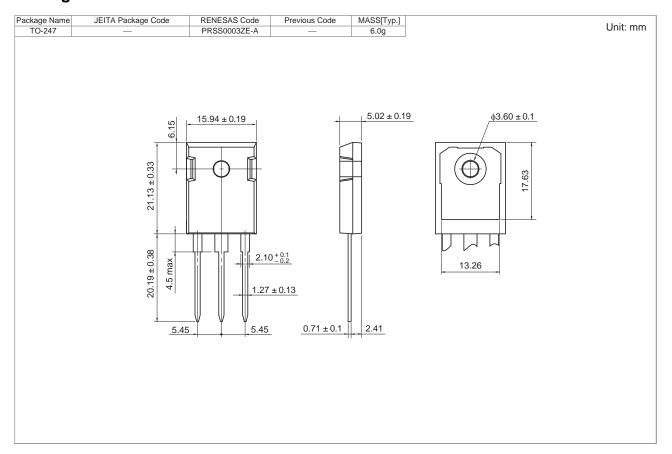
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
|---|-----------------------------------|-----|------|-----|------|--|
| Zero gate voltage collector current / Diode reverse current | I _{CES} / I _R | _ | _ | 5 | μА | V _{CE} = 1200 V, V _{GE} = 0 |
| Gate to emitter leak current | I _{GES} | _ | _ | ±1 | μΑ | $V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$ |
| Gate to emitter cutoff voltage | $V_{GE(off)}$ | 4 | _ | 8 | V | V _{CE} = 10 V, I _C = 1 mA |
| Collector to emitter saturation voltage | V _{CE(sat)} | _ | 2.1 | _ | V | $I_C = 25 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$ |
| Input capacitance | Cies | _ | 2000 | _ | pF | V _{CE} = 25 V |
| Output capacitance | Coes | _ | 70 | _ | pF | V _{GE} = 0 f = 1 MHz |
| Reveres transfer capacitance | Cres | _ | 45 | _ | pF | |
| Switching time | t _{d(on)} | _ | 50 | _ | ns | V _{CC} = 600 V, V _{GE} = 15 V |
| | t _r | _ | 20 | _ | ns | $I_C = 25 \text{ A}$ $Rg = 5 \Omega$ Inductive load |
| | t _{d(off)} | _ | 110 | _ | ns | |
| | t _f | _ | 100 | _ | ns | |
| Short circuit withstand time | t _{sc} | _ | 10 | _ | μS | $V_{CC} \le 720 \text{ V}, V_{GE} = 15 \text{ V}$ $Tc \le 125^{\circ}C$ |

| FRD forward voltage | V_{F} | _ | 1.7 | _ | V | I _F = 25 A ^{Note3} |
|---------------------------|-----------------|---|-----|---|----|--|
| FRD reverse recovery time | t _{rr} | _ | 200 | _ | ns | I _F = 25 A |
| | | | | | | di _F /dt = 100 A/μs |

Notes: 3. Pulse test.

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Package Dimension



Ordering Information

| Orderable Part Number | Quantity | Shipping Container |
|-----------------------|----------|--------------------|
| RJH1CM7DPQ-E0#T2 | 450 pcs | Box (Tube) |

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